



#### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BVDSS	Rds(on) max	I <sub>D</sub> T <sub>A</sub> = +25°C
201/	0.3Ω @ V <sub>GS</sub> = -4.5V	-0.9A
-20V	0.5Ω @ V <sub>GS</sub> = -2.5V	-0.7A

## **Description**

This MOSFET has been designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- DC-DC Converters
- Power Management Functions





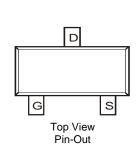
Top View

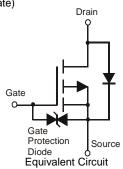
#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

#### **Mechanical Data**

- Package: SC59
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.014 grams (Approximate)





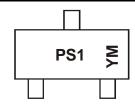
## **Ordering Information** (Note 4)

Part Number	Compliance	Package	Packing		
Fait Number	Compliance	Fackage	Qty.	Carrier	
DMP2012SN-7	Standard	SC59	3000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



PS1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Kev

Year	2006		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Т		I	J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	VDSS	-20	V
Gate-Source Voltage	Vgss	±12	V
Drain Current (Note 5) Steady State	ID	-0.9	Α
Pulsed Drain Current (Note 6)	I <sub>DM</sub>	-2.8	Α

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	500	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	250	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

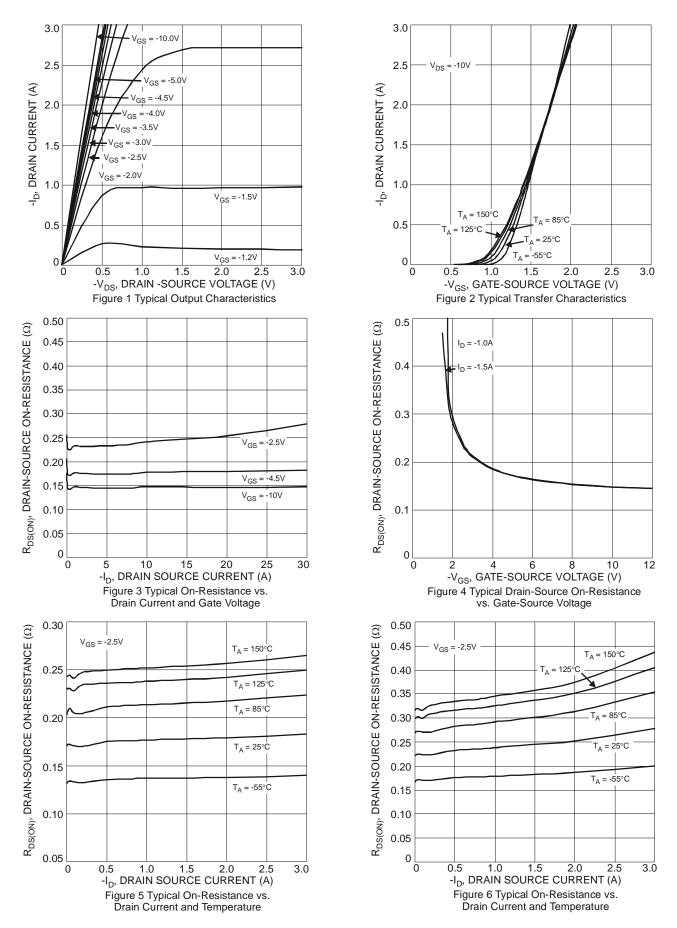
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_		V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-10	μΑ	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Body Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	-0.5	_	-1.2	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	0.23 0.37	0.3 0.5	Ω	$V_{GS} = -4.5V, I_{D} = -0.4A$ $V_{GS} = -2.5V, I_{D} = -0.4A$
Forward Transfer Admittance	Y <sub>fs</sub>	_	1.5		S	$V_{DS} = -10V, I_{D} = -0.4A$
Diode Forward Voltage (Note 7)	$V_{SD}$	_	-0.8	-1.1	V	$V_{GS} = 0V, I_{S} = -0.7A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	_	178.5		pF	101/11/
Output Capacitance	Coss	_	26.3		pF	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	18.8	_	pF	1 = 1.01/11 12
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	td(ON)	_	10.4	l	ns	
Turn-Off Delay Time	tD(OFF)	_	175	1	ns	$V_{DD} = -10V, I_{D} = -0.4A,$
Turn-On Rise Time	tr		22.3	_	ns	$V_{GS} = -5.0V$ , $R_{GEN} = 50\Omega$
Turn-Off Fall Time	tf	_	64	_	ns	

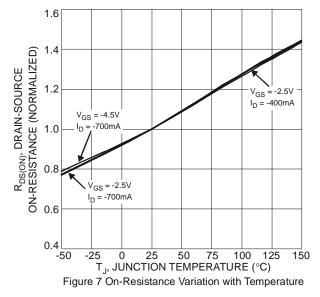
Notes:

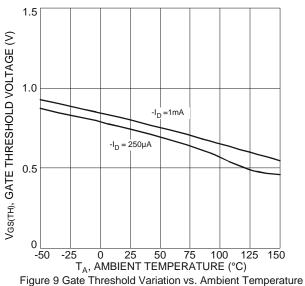
- 5. Device mounted on FR-4 PCB.
- 6. Pulse width ≤10μS, Duty Cycle ≤1%.
  7. Short duration pulse test used to minimize self-heating effect.

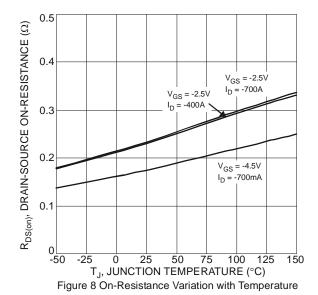


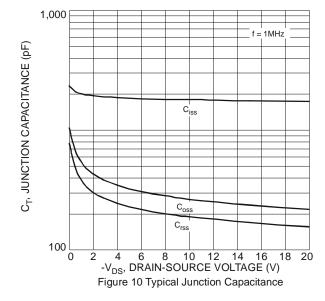










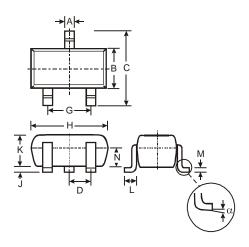




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SC59

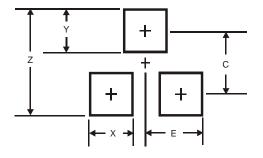


SC59						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	-		0.95			
G	-	-	1.90			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
М	0.10	0.20	0.15			
N	0.70	0.80	0.75			
α	0°	8°	-			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
Z	3.4
Х	0.8
Υ	1.0
С	2.4
F	1.35



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